

GNSS LOW NOISE AMPLIFIER

■ GENERAL DESCRIPTION

The NJG1150UA2 is a low noise amplifier GaAs MMIC designed for GNSS (Global Navigation Satellite Systems).

The NJG1150UA2 is featured low noise figure and low distortion, and operates from 1.5V to 3.3V single voltage. The NJG1150UA2 has stand-by mode to save the supply current, has the on-chip ESD protection devices.

The NJG1150UA2 achieves very small mounting area by only two external components and very small package that is lead-free and halogen-free 6-pin EPFFP6-A2 package.

■ PACKAGE OUTLINE



NJG1150UA2

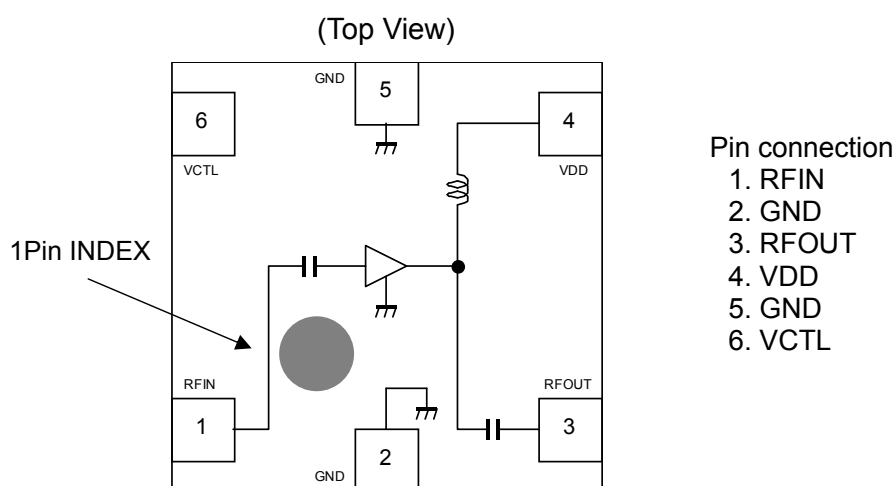
■ APPLICATIONS

GNSS applications, like GPS, Galileo, GLONASS and COMPASS.

■ FEATURES

- Low supply voltage 1.8/ 2.8V typ.
- Low current consumption 4.2 / 4.9mA typ. @ $V_{DD}=1.8/ 2.8V$, $V_{CTL}=1.8V$
0.1 μ A typ. @ $V_{DD}=1.8/ 2.8V$, $V_{CTL}=0V$ (Stand-by mode)
- High gain 16.0dB typ. @ $V_{DD}=1.8/ 2.8V$, $V_{CTL}=1.8V$, $f=1575MHz$
- Low noise figure 0.6dB typ. @ $V_{DD}=1.8/ 2.8V$, $V_{CTL}=1.8V$, $f=1575MHz$
- High input IP3 -1 / +1dBm typ. @ $V_{DD}=1.8/ 2.8V$, $V_{CTL}=1.8V$, $f=1575+1575.1MHz$
- High out of band input IP3 +5 / +6dBm typ. @ $V_{DD}=1.8/ 2.8V$, $V_{CTL}=1.8V$, $f=1712.7+1850MHz$
- Small package EPFFP6-A2 (Package size: 1.0mmx1.0mmx0.37mm typ.)
- RoHS compliant and Halogen Free
- MSL1

■ PIN CONFIGURATION



■ TRUTH TABLE

"H"= $V_{CTL}(H)$, "L"= $V_{CTL}(L)$	
VCTL	LNA Mode
H	Active mode
L	Stand-by mode

Note: Specifications and description listed in this datasheet are subject to change without notice.

■ ABSOLUTE MAXIMUM RATINGS

$T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\Omega$

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	V_{DD}		5.0	V
Control voltage	V_{CTL}		5.0	V
Input power	P_{IN}	$V_{DD}=2.8\text{V}$	+15	dBm
Power dissipation	P_D	4-layer FR4 PCB with through-hole (101.5mmx114.5mm), $T_j=150^{\circ}\text{C}$	590	mW
Operating temperature	T_{opr}		-40~+85	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-55~+150	$^{\circ}\text{C}$

■ ELECTRICAL CHARACTERISTICS 1 (DC)

General conditions: $T_a=+25^{\circ}\text{C}$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{DD}		1.5	-	3.3	V
Control Voltage (High)	$V_{CTL(H)}$		1.5	1.8	3.3	V
Control Voltage (Low)	$V_{CTL(L)}$		0	0	0.3	V
Supply Current1	I_{DD1}	Active mode, $V_{DD}=2.8\text{V}$, $V_{CTL}=1.8\text{V}$	-	4.9	8.0	mA
Supply Current2	I_{DD2}	Active mode, $V_{DD}=1.8\text{V}$, $V_{CTL}=1.8\text{V}$	-	4.2	7.0	mA
Supply Current3	I_{DD3}	Stand-by mode, $V_{DD}=2.8\text{V}$, $V_{CTL}=0\text{V}$	-	0.1	3.0	μA
Supply Current4	I_{DD4}	Stand-by mode, $V_{DD}=1.8\text{V}$, $V_{CTL}=0\text{V}$	-	0.1	3.0	μA
Control Current	I_{CTL}	$V_{CTL}=1.8\text{V}$	-	5.0	12.0	μA

■ ELECTRICAL CHARACTERISTICS 2 (RF)

General conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $f_{RF}=1555\sim 1610MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit1

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small Signal Gain1	Gain1	Exclude PCB and connector Losses (0.17dB)	14.5	16.0	17.0	dB
Noise Figure1	NF1	Exclude PCB and connector Losses (0.08dB)	-	0.6	0.9	dB
Input Power at 1dB Gain Compression Point1	P_{-1dB} (IN)1		-12.0	-7.0	-	dBm
Input 3rd Order Intercept Point1	IIP3_1	$f_1=f_{RF}$, $f_2=f_1\pm 1MHz$, Pin=-30dBm	-1.0	+1.0	-	dBm
Out of Band Input 3rd Order Intercept Point1	IIP3_OB1	$f_1=1712.7MHz$ Pin =-20dBm, $f_2=1850MHz$ Pin =-65dBm	+2.0	+6.0	-	dBm
700MHz Harmonic1	2fo1	Input jammer tone: 787.76MHz at -25dBm Measure the harmonic tone at 1575.52MHz	-	-45.0	-	dBm
RF IN VSWR1	VSWRi1		-	1.9	2.4	-
RF OUT VSWR1	VSWRo1		-	1.8	2.3	-

■ ELECTRICAL CHARACTERISTICS 3 (RF)

General conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{RF}=1555\sim 1610MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit2

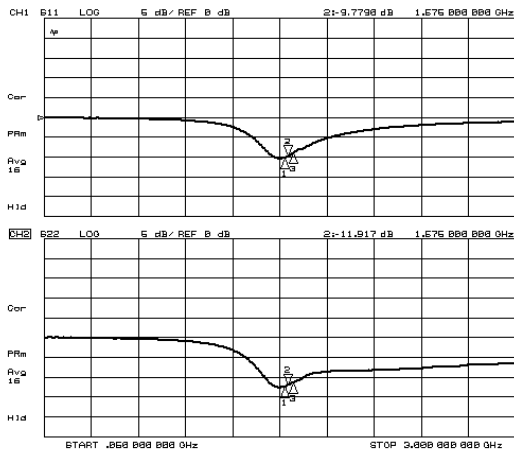
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small Signal Gain2	Gain2	Exclude PCB and connector Losses (0.17dB)	14.0	16.0	17.0	dB
Noise Figure2	NF2	Exclude PCB and connector Losses (0.08dB)	-	0.6	0.95	dB
Input Power at 1dB Gain Compression Point2	P_{-1dB} (IN)2		-14.0	-9.0	-	dBm
Input 3rd Order Intercept Point2	IIP3_2	$f_1=f_{RF}$, $f_2=f_1\pm 1MHz$, Pin=-30dBm	-6.0	-1.0	-	dBm
Out of Band Input 3rd Order Intercept Point2	IIP3_OB2	$f_1=1712.7MHz$ Pin =-20dBm, $f_2=1850MHz$ Pin =-65dBm	-1.0	+5.0	-	dBm
700MHz Harmonic2	2fo2	Input jammer tone: 787.76MHz at -25dBm Measure the harmonic tone at 1575.52MHz	-	-45.0	-	dBm
RF IN VSWR2	VSWRi2		-	1.9	2.6	-
RF OUT VSWR2	VSWRo2		-	1.8	2.5	-

■ TERMINAL INFORMATION

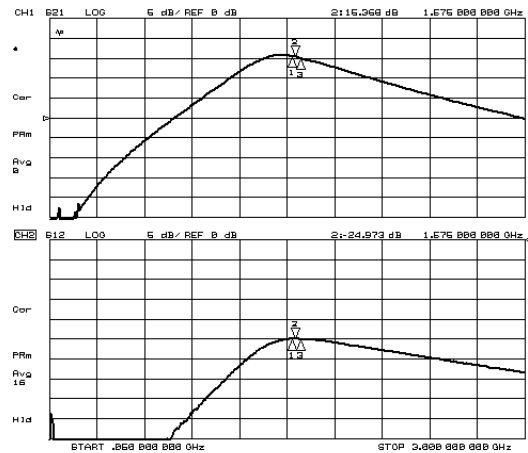
No.	SYMBOL	DESCRIPTION
1	RFIN	RF input terminal. This terminal requires only a matching inductor L1, and does not require DC blocking capacitor.
2	GND	Ground terminal. This terminal should be connected to the ground plane as close as possible for excellent RF performance.
3	RFOUT	RF output terminal. This terminal requires no DC blocking capacitor since this IC has internal output matching circuit including DC blocking capacitor.
4	VDD	Supply voltage terminal. Please connect bypass capacitor C1 with ground as close as possible.
5	GND	Ground terminal. This terminal should be connected to the ground plane as close as possible for excellent RF performance.
6	VCTL	Control voltage terminal.

ELECTRICAL CHARACTERISTICS

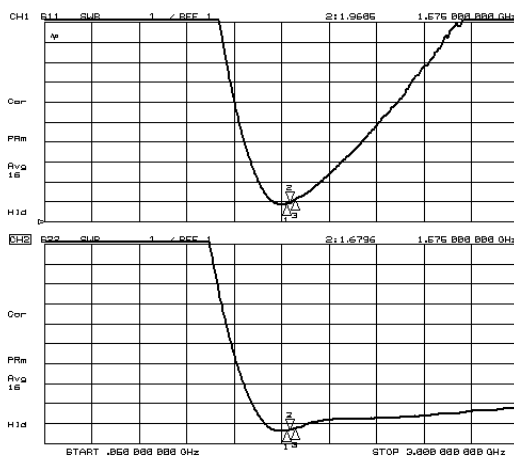
Conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $T_a=25^\circ C$, $Z_s=Z_l=50\Omega$, with application circuit1



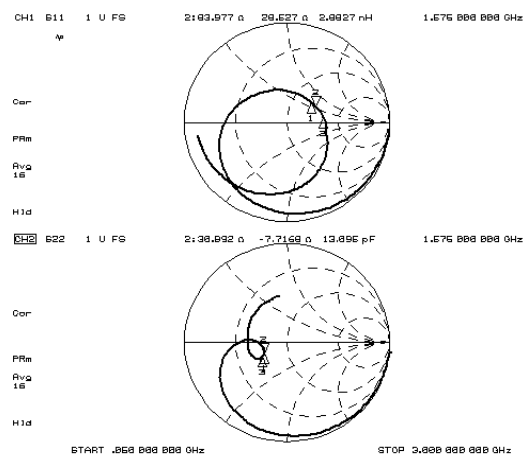
S11, S22



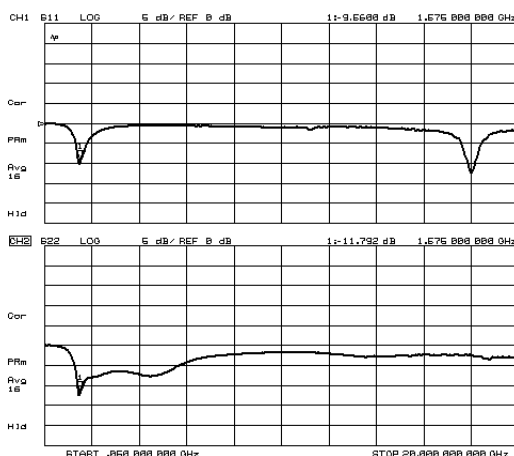
S21, S12



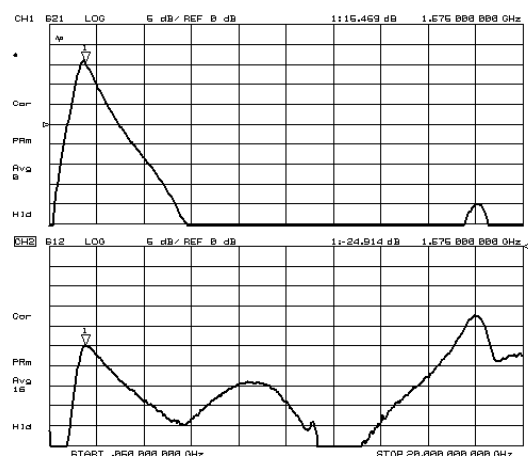
VSWRi, VSWRo



Zin, Zout



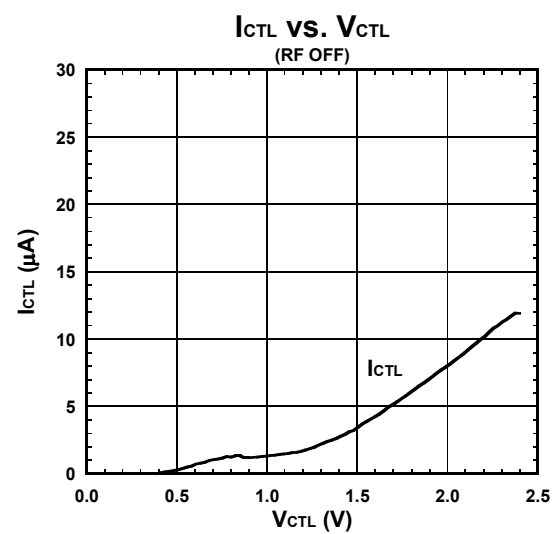
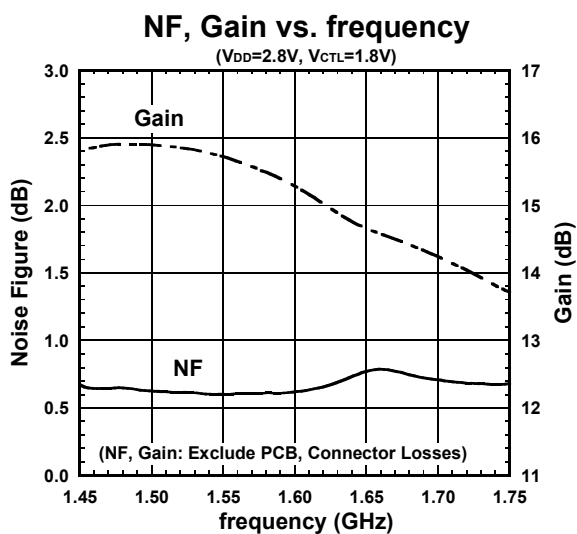
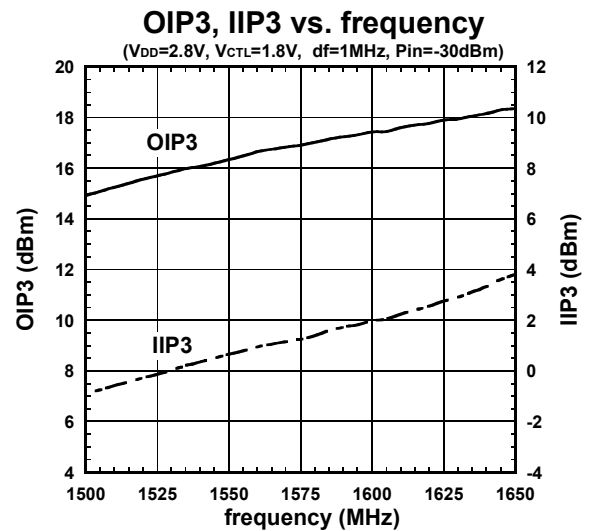
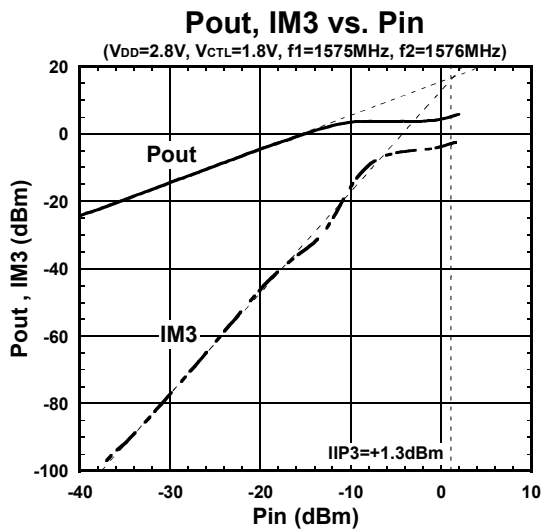
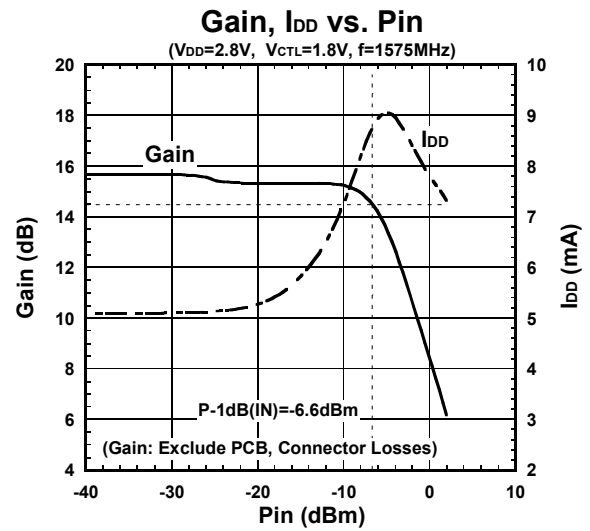
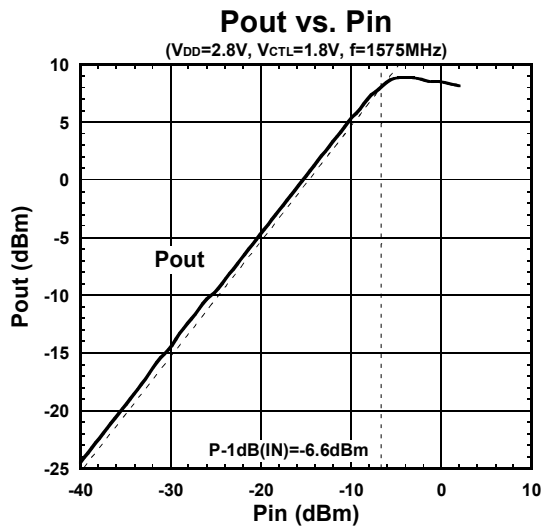
S11, S22 (50M~20GHz)



S21, S12 (50M~20GHz)

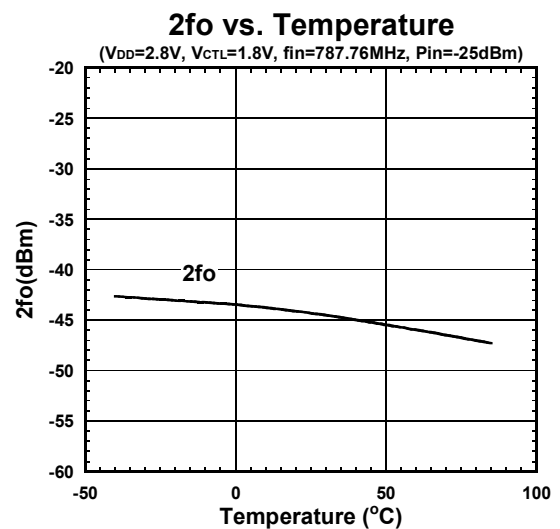
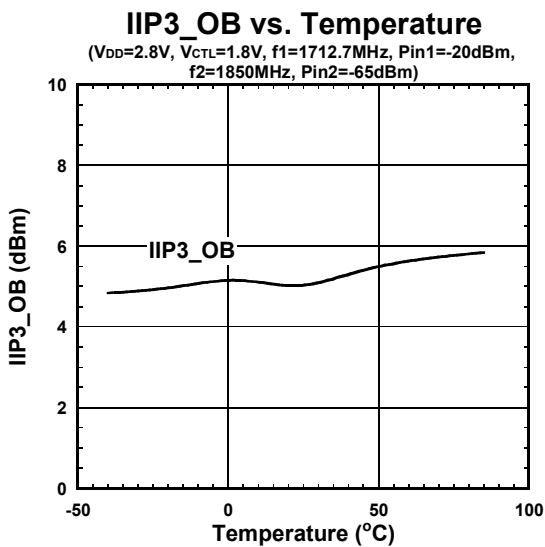
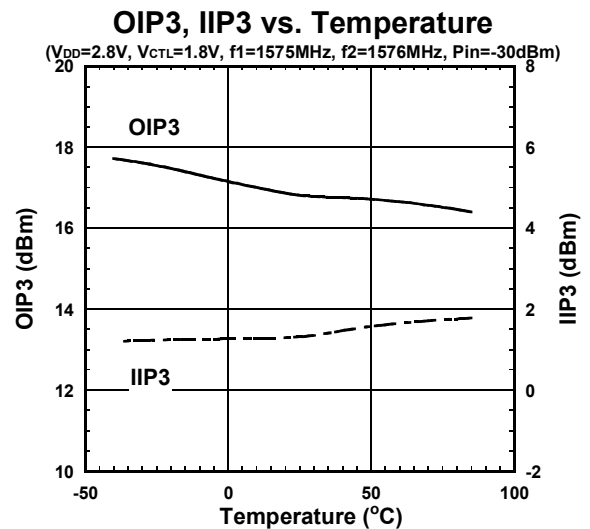
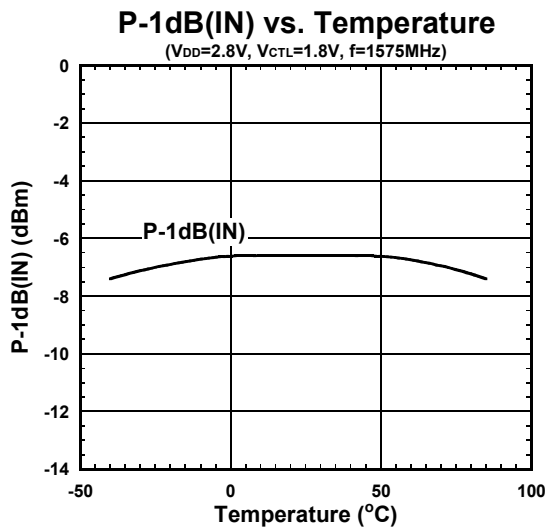
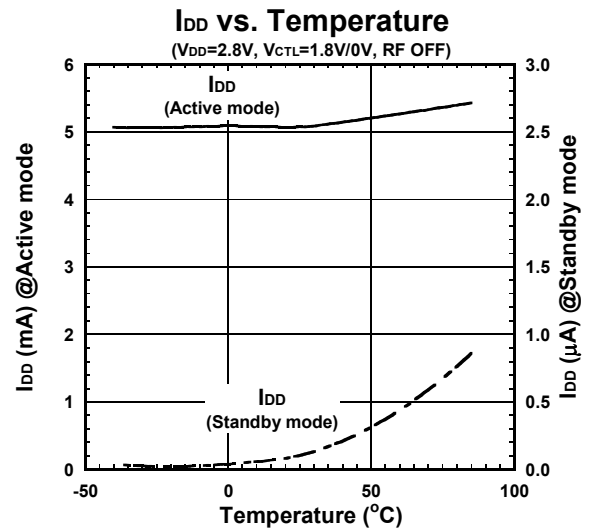
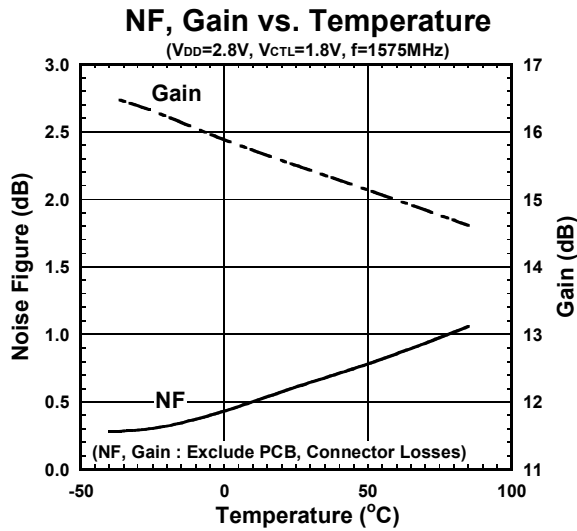
ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $T_a=25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit1



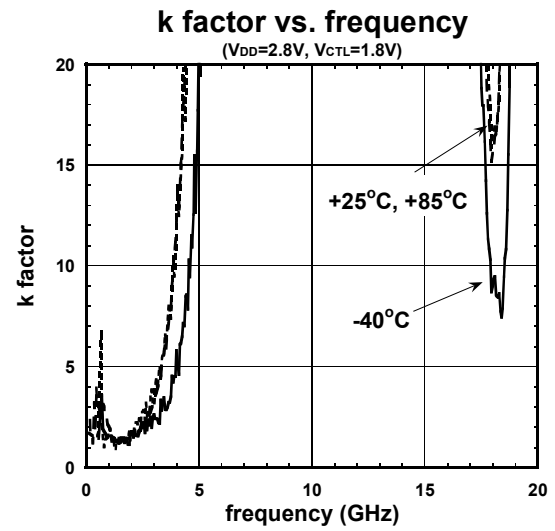
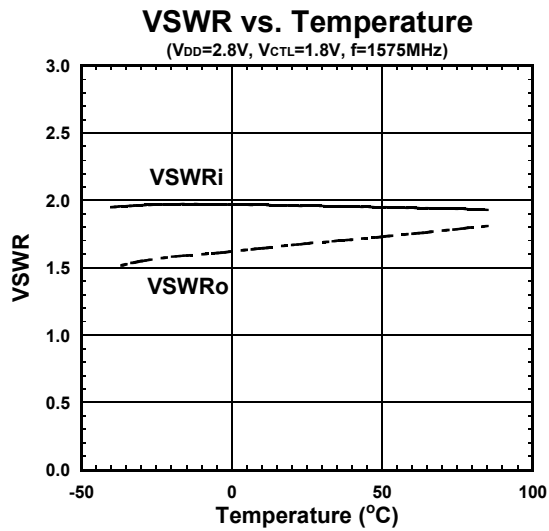
ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $Z_s=Z_l=50\Omega$, with application circuit1



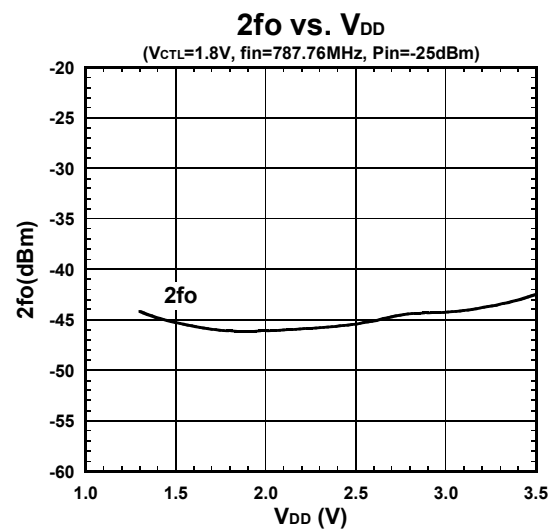
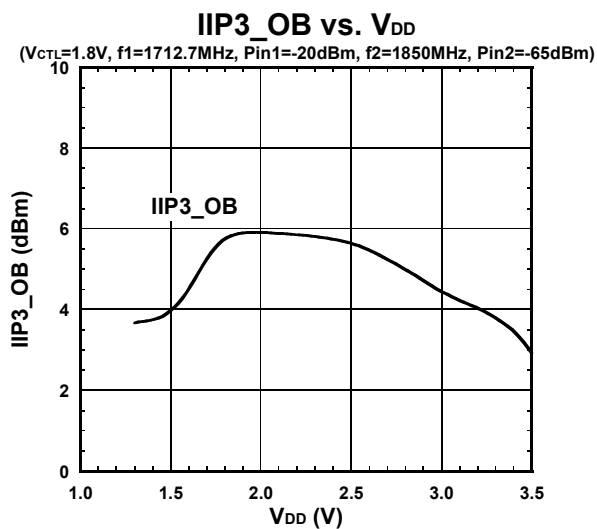
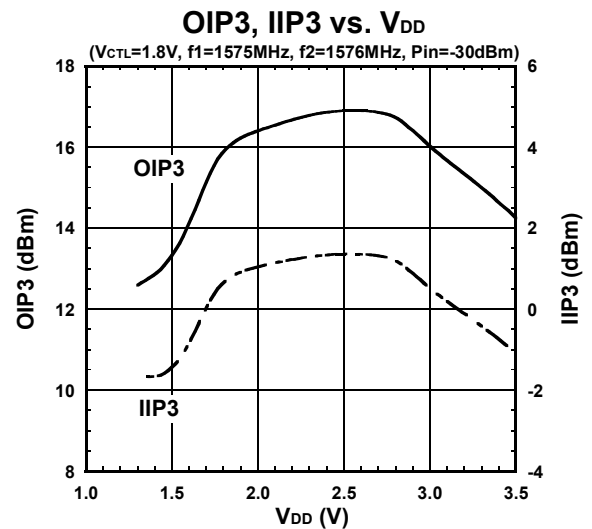
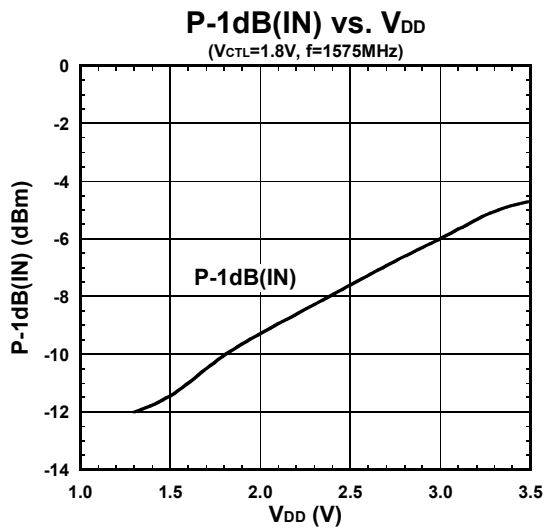
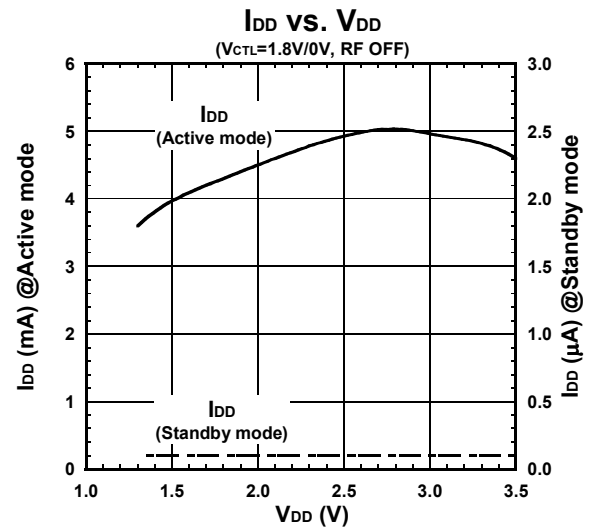
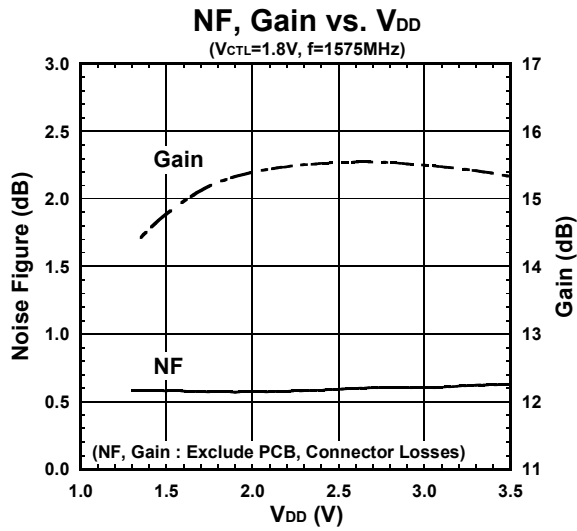
■ ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=2.8V$, $V_{CTL}=1.8V$, $Z_s=Z_l=50\Omega$, with application circuit1



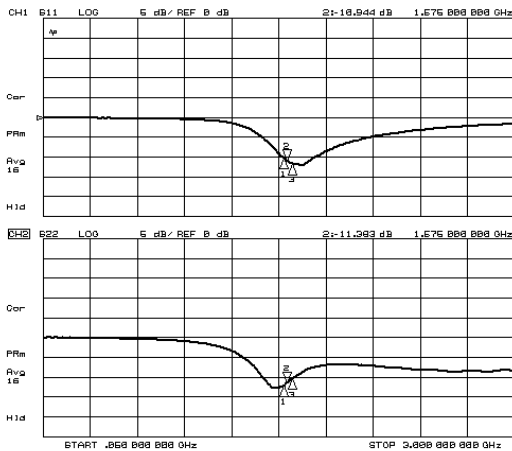
ELECTRICAL CHARACTERISTICS

Conditions: $V_{CTL}=1.8V$, $T_a=25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit1



ELECTRICAL CHARACTERISTICS

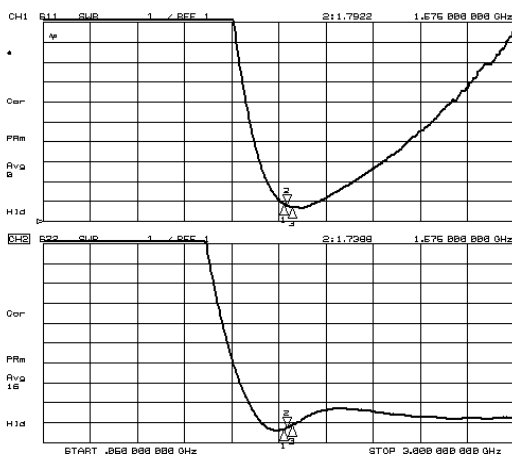
Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $T_a=25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit2



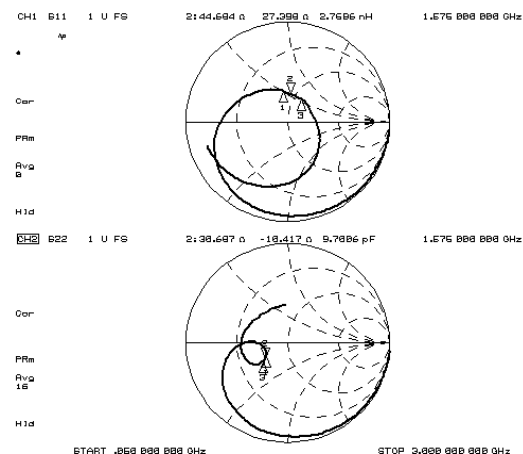
S11, S22



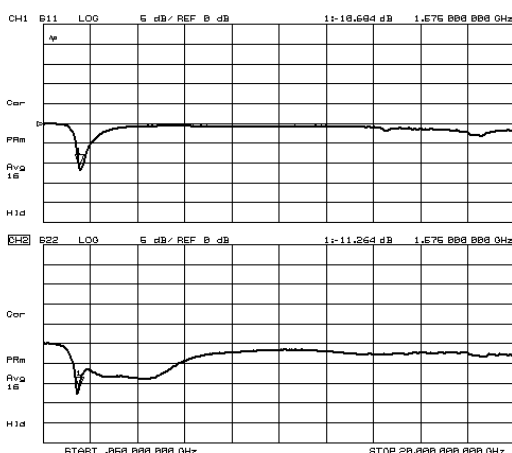
S21, S12



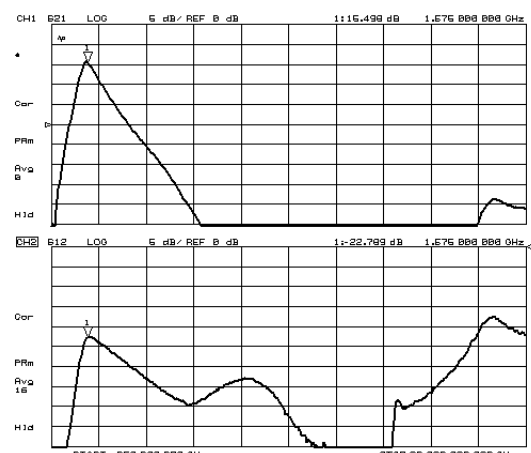
VSWRi, VSWRo



Zin, Zout



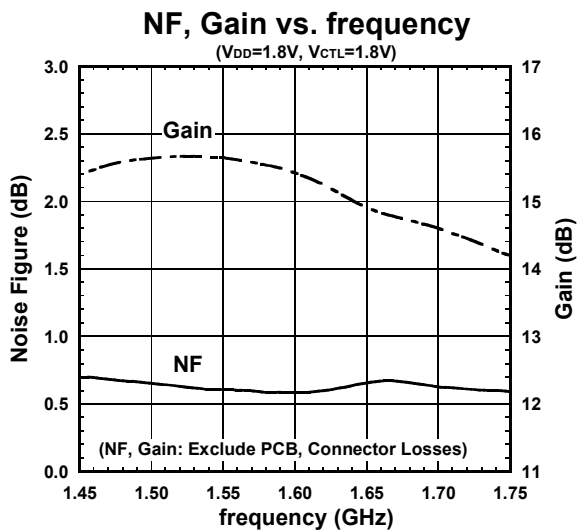
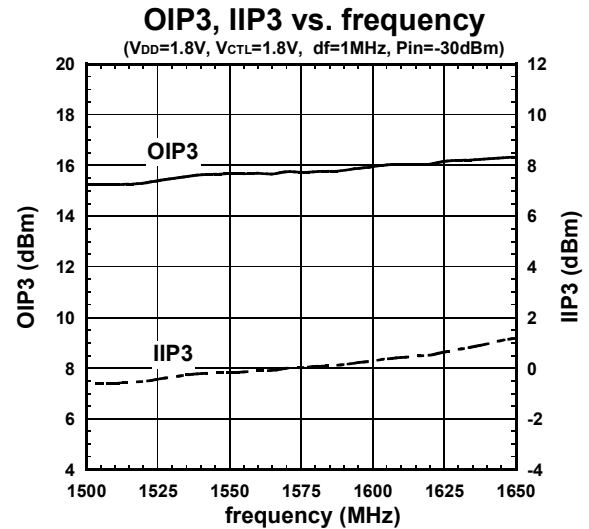
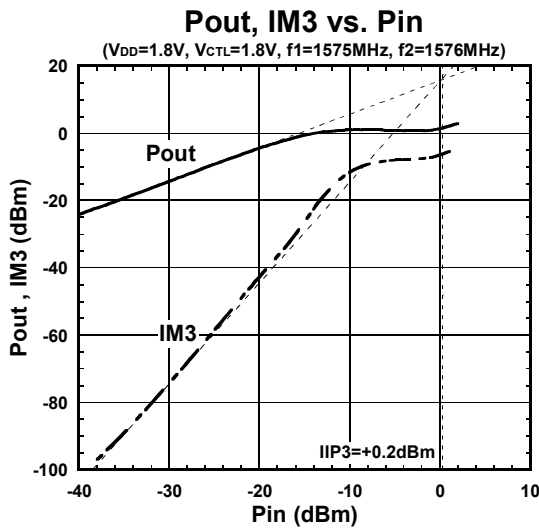
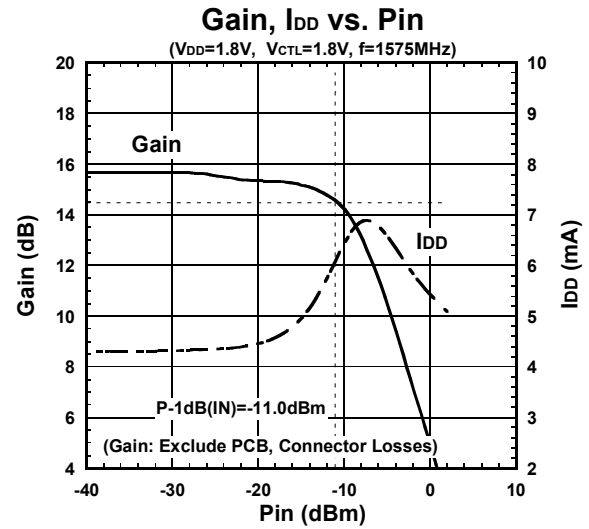
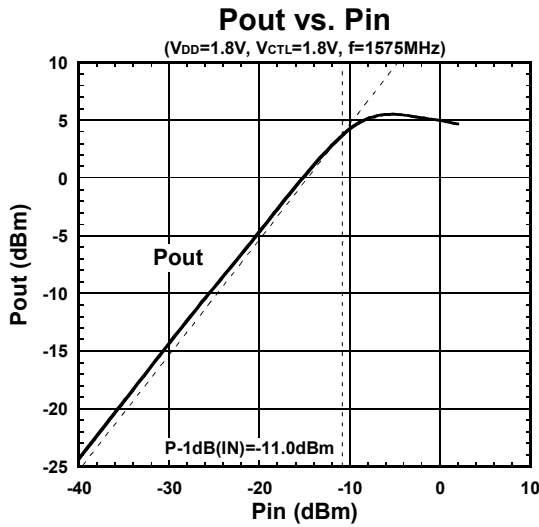
S11, S22 (50M~20GHz)



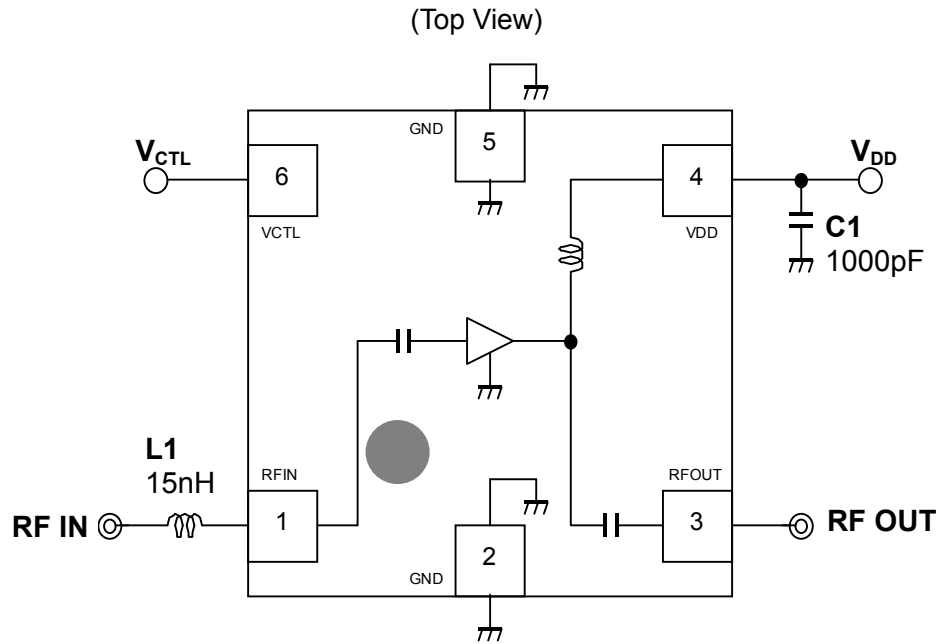
S21, S12 (50M~20GHz)

ELECTRICAL CHARACTERISTICS

Conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $T_a=25^\circ C$, $Z_s=Z_L=50\Omega$, with application circuit2



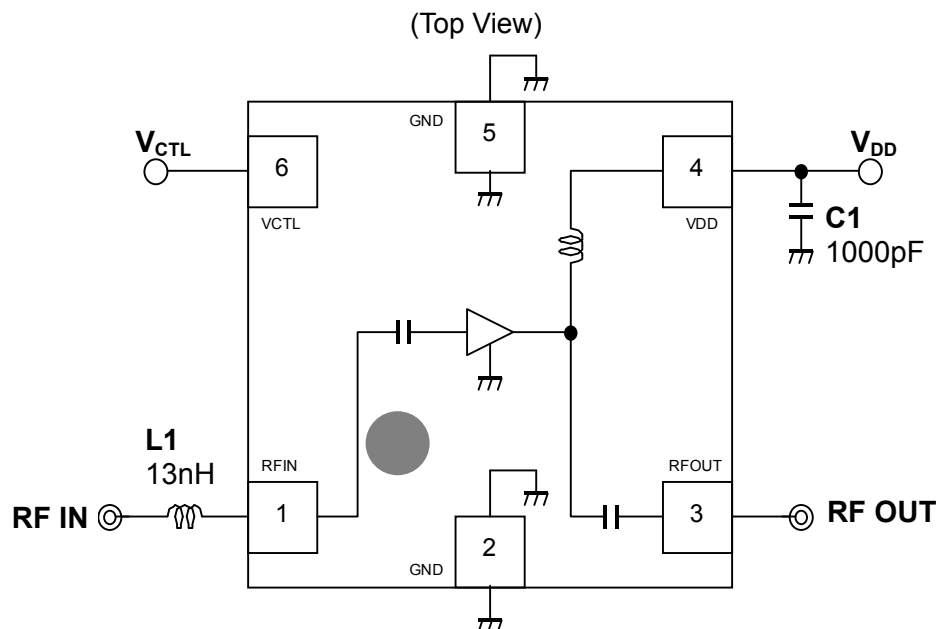
■ APPLICATION CIRCUIT1 ($V_{DD}=2.8V$)



Parts list

Parts ID	Manufacture
L1	LQW15A Series (MURATA)
C1	GRM03 Series (MURATA)

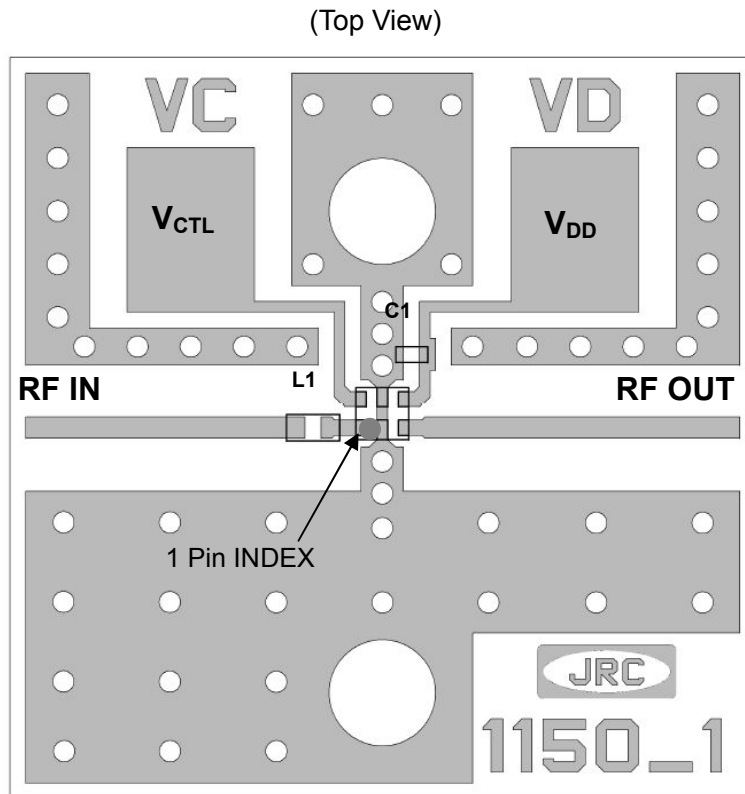
■ APPLICATION CIRCUIT2 ($V_{DD}=1.8V$)



Parts list

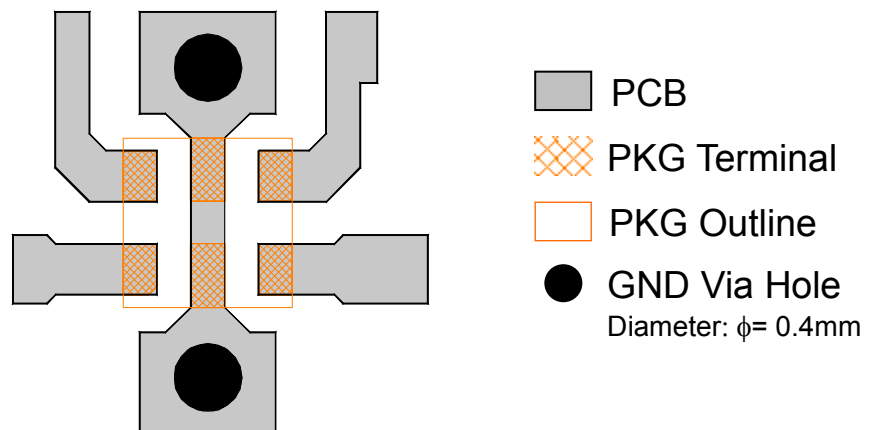
Parts ID	Manufacture
L1	LQW15A Series (MURATA)
C1	GRM03 Series (MURATA)

■ EVALUATION BOARD



PCB (FR-4):
 $t=0.2\text{mm}$
 MICROSTRIP LINE WIDTH
 $=0.4\text{mm}$ ($Z_0=50\Omega$)
 PCB SIZE
 $=14.0\text{mm} \times 14.0\text{mm}$

<PCB LAYOUT GUIDELINE>



PRECAUTIONS

- Please layout ground pattern under this IC in order not to couple with terminal RFIN and RFOUT.
- All external parts should be placed as close as possible to the IC.
- For good RF performance, all GND terminals must be connected to PCB ground plane of substrate, and via-holes for GND should be placed near the IC.

■ RECOMMENDED FOOTPRINT PATTERN (EPFFP6-A2 PACKAGE Reference)

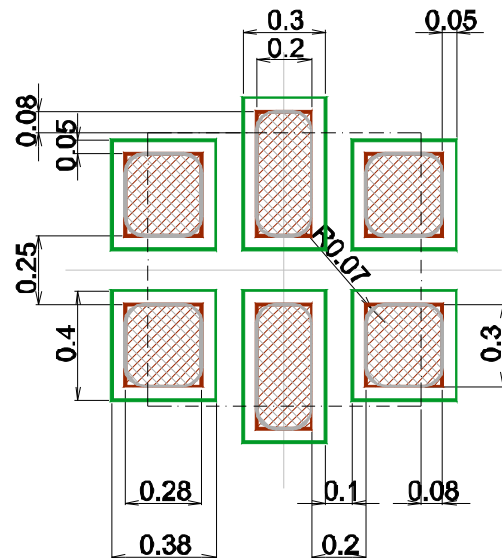
 : Land

 : Mask (Open area) *Metal mask thickness: 100um

 : Resist (Open area)

Package: 1.0 x 1.0mm

Pin pitch: 0.4mm



APPLICATION NOTE FOR SMALLER MOUNTING AREA (using MLG0603P Series inductor)

This application note shows an example in order to achieve smaller mounting area using smaller size external inductor L1. MLG0603P (TDK-EPC) Series inductor is used for this application. The example of electrical characteristics are shown as follows:

■ ELECTRICAL CHARACTERISTICS 4 (DC)

General conditions: $T_a=+25^{\circ}\text{C}$

PARAMETER	SYMBOL	CONDITIONS	MEASURED DATA	UNITS
Supply Voltage	V_{DD}		2.8 / 1.8	V
Control Voltage (High)	$V_{CTL(H)}$		1.8	V
Control Voltage (Low)	$V_{CTL(L)}$		0	V
Supply Current1	I_{DD1}	Active mode, $V_{DD}=2.8\text{V}$, $V_{CTL}=1.8\text{V}$	5.04	mA
Supply Current2	I_{DD2}	Active mode, $V_{DD}=1.8\text{V}$, $V_{CTL}=1.8\text{V}$	4.33	mA
Supply Current3	I_{DD3}	Stand-by mode, $V_{DD}=2.8\text{V}$, $V_{CTL}=0\text{V}$	0.1	μA
Supply Current4	I_{DD4}	Stand-by mode, $V_{DD}=1.8\text{V}$, $V_{CTL}=0\text{V}$	0.1	μA
Control Current	I_{CTL}	$V_{CTL}=1.8\text{V}$	6.0	μA

■ ELECTRICAL CHARACTERISTICS 5 (RF)

General conditions: $V_{DD}=2.8\text{V}$, $V_{CTL}=1.8\text{V}$, $f_{RF}=1555\sim 1610\text{MHz}$, $T_a=+25^{\circ}\text{C}$, $Z_s=Z_l=50\Omega$, with application circuit3

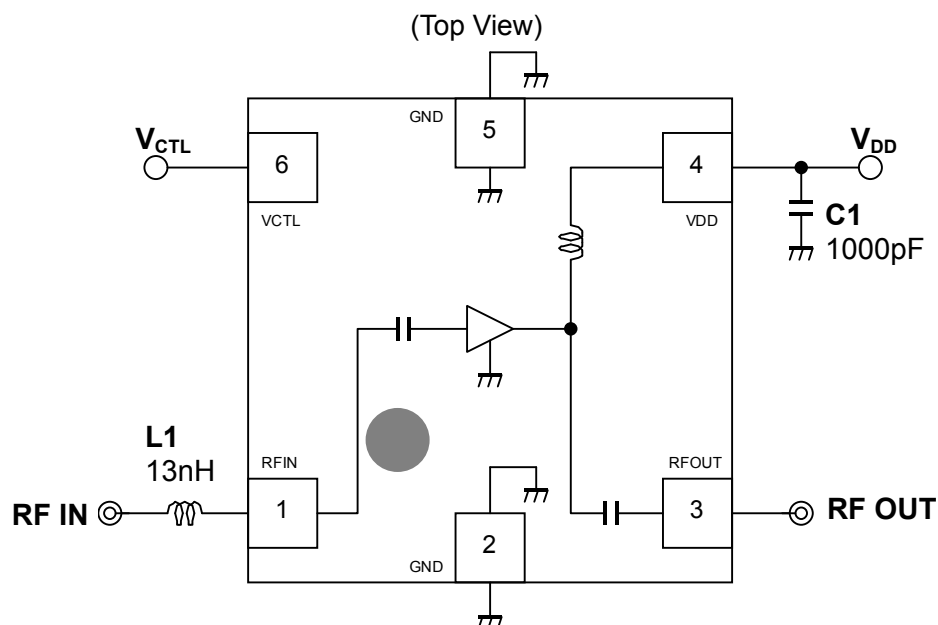
PARAMETER	SYMBOL	CONDITIONS	MEASURED DATA	UNITS
Small Signal Gain5	Gain5	Exclude PCB and connector Losses	15.3~15.7	dB
Noise Figure5	NF5	Exclude PCB and connector Losses	0.80~0.84	dB
Input Power at 1dB Gain Compression Point5	P_{-1dB} (IN)5		-8.6~-6.6	dBm
Input 3rd Order Intercept Point5	IIP3_5	$f_1=f_{RF}$, $f_2=f_1\pm 1\text{MHz}$, $\text{Pin}=-30\text{dBm}$	+0.2~+1.5	dBm
Out of Band Input 3rd Order Intercept Point5	IIP3_OB5	$f_1=1712.7\text{MHz}$ $\text{Pin}=-20\text{dBm}$, $f_2=1850\text{MHz}$ $\text{Pin}=-65\text{dBm}$	+4.3	dBm
700MHz Harmonic5	2fo5	Input jammer tone: 787.76MHz at -25dBm Measure the harmonic tone at 1575.52MHz	-44.8	dBm
RF IN VSWR5	VSWRi5		1.54~1.60	-
RF OUT VSWR5	VSWRo5		1.54~1.69	-

■ ELECTRICAL CHARACTERISTICS 6 (RF)

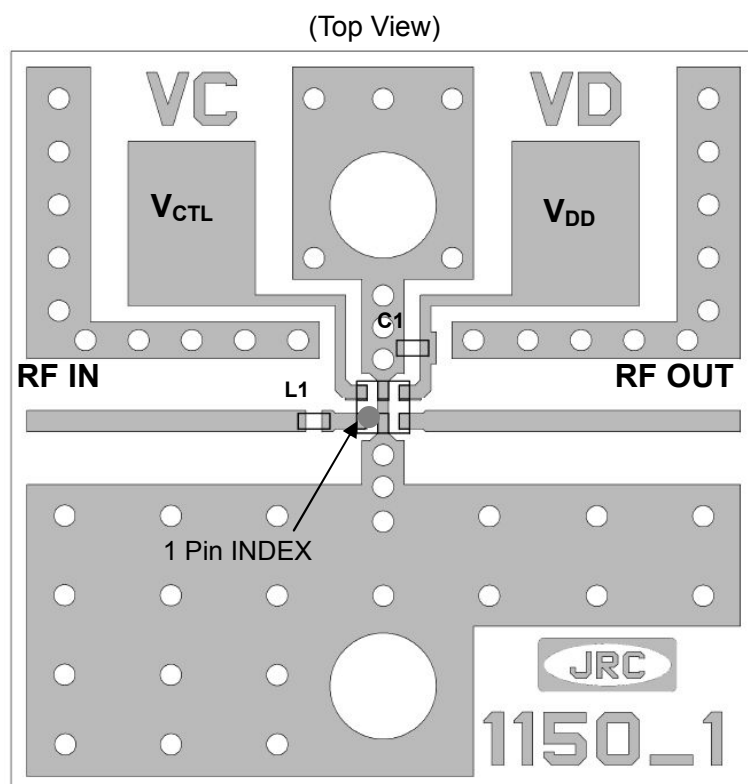
General conditions: $V_{DD}=1.8V$, $V_{CTL}=1.8V$, $f_{RF}=1555\sim1610MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_l=50\Omega$, with application circuit3

PARAMETER	SYMBOL	CONDITIONS	MEASURED DATA	UNITS
Small Signal Gain6	Gain6	Exclude PCB and connector Losses	14.9~15.4	dB
Noise Figure6	NF6	Exclude PCB and connector Losses	0.77~0.83	dB
Input Power at 1dB Gain Compression Point6	P_{-1dB} (IN)6		-10.5 ~ -10.0	dBm
Input 3rd Order Intercept Point6	IIP3_6	$f_1=f_{RF}$, $f_2=f_1\pm 1MHz$, $P_{in}=-30dBm$	+0.5 ~ +1.2	dBm
Out of Band Input 3rd Order Intercept Point6	IIP3_OB6	$f_1=1712.7MHz$ $P_{in}=-20dBm$, $f_2=1850MHz$ $P_{in}=-65dBm$	+5.8	dBm
700MHz Harmonic6	2fo6	Input jammer tone: 787.76MHz at -25dBm Measure the harmonic tone at 1575.52MHz	-45.5	dBm
RF IN VSWR6	VSWRi6		1.67~1.78	-
RF OUT VSWR6	VSWRo6		1.87~2.11	-

■ APPLICATION CIRCUIT3 (Using MLG0603P Series inductor)



■ EVALUATION BOARD (Using MLG0603P Series)



PCB (FR-4):
 $t=0.2\text{mm}$
 MICROSTRIP LINE WIDTH
 $=0.4\text{mm}$ ($Z_0=50\Omega$)
 PCB SIZE
 $=14.0\text{mm} \times 14.0\text{mm}$

■ NOISE FIGURE MEASUREMENT BLOCK DIAGRAM

Measuring instruments

NF Analyzer : Agilent N8973A
Noise Source : Agilent 346A

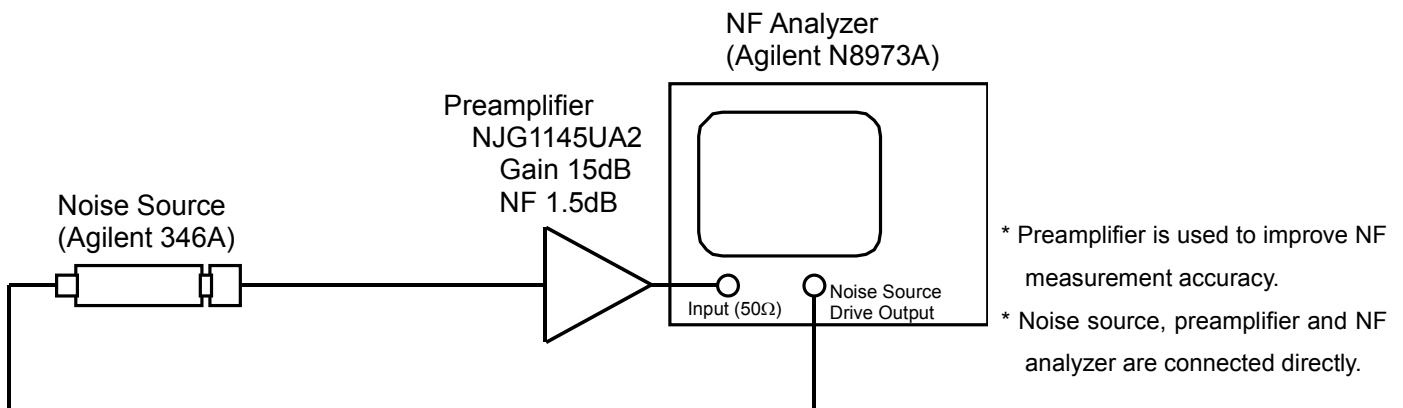
Setting the NF analyzer

Measurement mode form

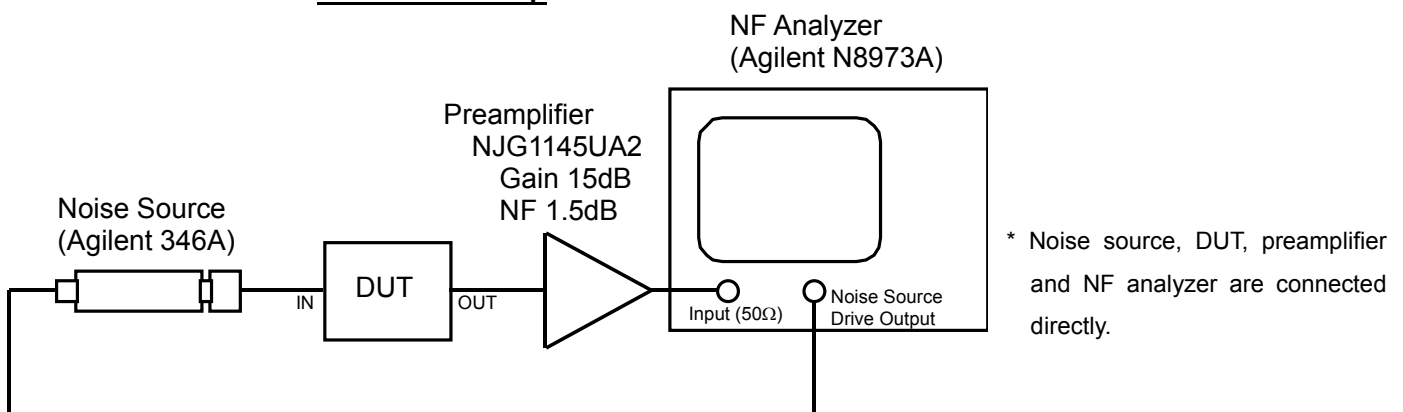
Device under test : Amplifier
System downconverter : off

Mode setup form

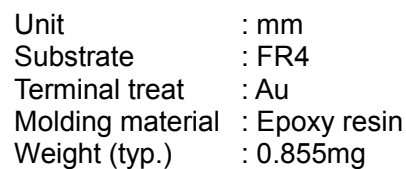
Sideband : LSB
Averages : 16
Average mode : Point
Bandwidth : 4MHz
Loss comp : off
Tcold : setting the temperature of noise source (303.15K)



Calibration setup



Measurement Setup



Mouser Electronics

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Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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